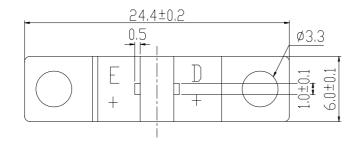
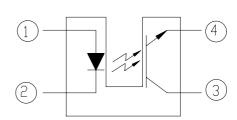
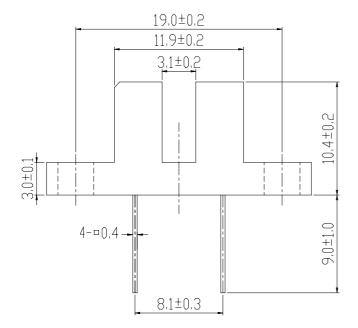


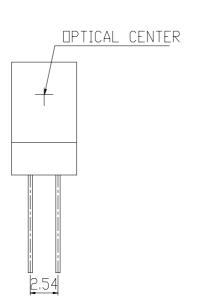


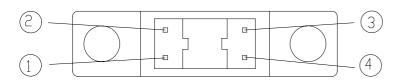
■ Package Dimensions :











- (1):Anode
- (2):Cathode
- (3):Collector
- 4):Emitter

DESIGNER	CHECKER	APPROVED

Office: NO 25, Lane 76, Chung Yang Rd,, Sec. 3

Tucheng, Taipei 236, Taiwan, R.O.C.

TEL: 886-2-2267-2000,2267-9936(22Lines)



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⊚Notes:

- 1.All dimensions are in millimeter.
- 2.General Tolerance: ±0.2mm
- 3. Lead spacing is measured where the lead emerge from the package.
- 4. Above specification may be changed without notice. EVERLIGHT will reserve authority on material change for above specification.
- 5. These specification sheets include materials protected under copyright of EVERLIGHT corporation. Please don't reproduce or cause anyone to reproduce them without EVERLIGHT's consent.
- 6.When using this product , please observe the absolute maximum ratings and the instructions for use outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.

■ Descriptions:

The ITR8102(Slot Optical Switch) is a gallium arsenide infrared emitting diode which is coupled with a silicon photo transistor in a plastic housing. The packaging system is designed to optimizes the mechanical resolution, coupling efficiency, and insulates ambient light. The slot in the housing a provides a means of interrupting the signal with printer, scanner, copier, or other opaque material, switching the output from an "ON" to OFF" state.

Features:

- · Wide gap between light emitter and detector(3.1mm)
- · High sensing accuracy
- · PWB mounting type package
- · Pb free
- · The product itself will remain within RoHS compliant version.

Applications:

- · Copier
- · Printer
- · Facsimile
- · Ticket vending machine



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· Opto-electronic switch

■ Absolute Maximum Ratings (Ta=25°C)

	Parameter	Symbol	Ratings	Unit
	Power Dissipation at(or below) 25°C Free Air Temperature	Pd	75	mW
Input	Reverse Voltage	V_R	5	V
	Forward Current	$\mathtt{I}_{\mathtt{F}}$	50	mA
	Peak Forward Current Pulse width ≦100µs, Duty cycle=1%	$\mathtt{I}_{\mathtt{FP}}$	1	A
	Collector Power Dissipation	P_{C}	75	mW
Output	Collector Current	I_{C}	20	mA
	Collector-Emitter Voltage	V_{CEO}	30	V
	Emitter-Collector Voltage	V_{ECO}	5	V
Operating Temperature		Topr	-25~+85	°C
Storage	e Temperature	Tstg	-40~+85	°C
	Lead Soldering Temperature (1/16 inch from body for 5 seconds)		260	°C

Electro-Optical Characteristics (Ta=25°C)

Parameter		Symbol	Min.	Тур.	Max.	Unit	Condition
	Forward Voltage	$V_{\scriptscriptstyle F}$	-	1.2	1.6	V	$I_F = 20 mA$
Input	Reverse Current	I_{R}	-	_	10	μΑ	$V_R = 5V$
Inpuc	Peak Wavelength	λ_{P}	-	940	-	nm	$I_F = 20 mA$
	View Angle	2[1/2	-	60	-	Deg	$I_F = 20 mA$
Output	Collector Dark Current	$I_{ ext{CEO}}$	-	_	100	nA	V _{CE} =10V
Transfer Characteristic	C-E Saturation Voltage	V _{CE} (sat)	-	-	0.4	V	$I_{c}=0.5$ mA $I_{F}=20$ mA
	Collector Current	I _C (ON)	0.9	4	15	mA	$V_{CE}=5V$ $I_F=20mA$
	Rise time	tr	_	20	_	μsec	$V_{CE}=5V$



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Fall time	+		20			$I_{c}=1mA$
Fall time	c_{f}	_	20	_	μsec	$R_{L}=1K\Omega$

■ Typical Characteristics For IR

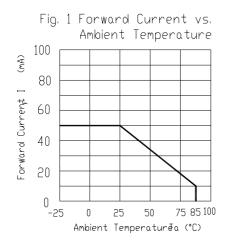


Fig. 3 Peak Emission Wavelength vs.
Ambient Temperature

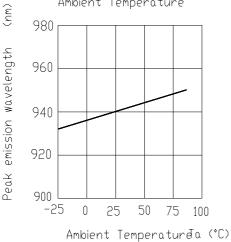
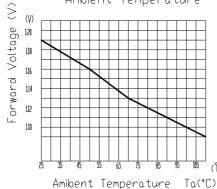


Fig. 5 Forward Voltage vs.
Ambient Temperature



🗦 Fig. 2 Spectral Distribution

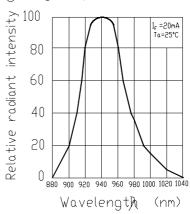


Fig. 4 Forward Current vs. Forward Voltage

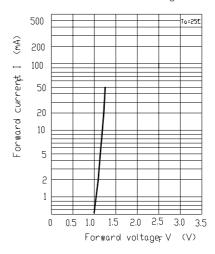
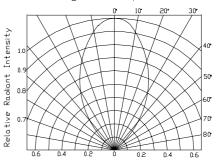


Fig. 6 Relative Radiant Intensity Angular Displacement





Typical Characteristics For PT

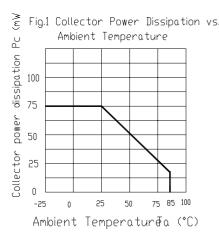


Fig.3 Spectral Sensitivity

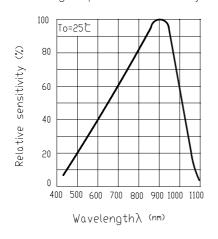


Fig.2 Collector Dark Current vs.

Ambient Temperature

VE =20V

10⁻⁶

VE =20V

10⁻⁸

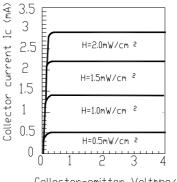
Ambient Temperature

Ambient Temperature

Ambient Temperature

Ambient Temperaturea (°C)

Fig.4 Collector Current vs.
Collector-emitter Voltage

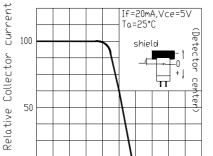


Collector-emitter Volt&ge(V)

Typical Characteristics For ITR

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Reliability test item and condition

The reliability of products shall be satisfied with item listed below:

Confidence level :90% LTPD:10%

Parameter	Purpose & Condition	Failure Judgement	Samples(n)
rarameter	r urpose & Condition	Criteria	
Temperature Cycle	Evaluates product's ability to withstand exposure to high temperature, low temperature, and temperature variation between two limit temperature. Standard test Condition: 85°C ~25°C ~ -55°C ~25°C 30min 5min 30min 5min 50 cycle	$I_R \ge U \times 2$ $I_C(on) \le L \times 0.8$ $V_F \ge U \times 1.2$ $U : Upper$ $specification$ $limit$ $L : Lower$ $specification$ $limit$	n =22 , c=0
Thermal Shock	Evaluates product's ability to withstand rapid temperature change Standard test Condition: 85°C ~ -55°C 5min 5min 50cycle		n =22 , c=0
High Temperature	Evaluates product's ability to		n =22 , c=0
Storage	withstand prolonged storage		
	at high temperature Standard		



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	test Condition:		
	Temperature:	100 °C	
	Time: 1000	Ohrs	
Low Temperature	Evaluates product's ability	to	$n = 22 \cdot c = 0$
Storage	withstand prolonged storag	ge	
	at low temperature Standar	rd	
	test Condition:		
	Temperature:	-55 °C	
	Time: 1000	Ohrs	

Parameter	Dumasa & Condition	Failure	Samples(n)
Parameter	Purpose & Condition	Judgement Criteria	Defective(c)
Operating Life Test	Evaluates product's endurance to prolonged electrical or temperature stresses. Standard test Condition: $V_{CE}{=}5V$ $I_{F}{=}20mA$	$I_R \geqq U \times 2$ $I_C(on) \leqq L \times 0.8$ $V_F \geqq U \times 1.2$ $U : Upper$	n =22 , c=0
	Time: 1000hrs	specification	
High Temperature High Humidity	Evaluates product's ability to withstand prolonged storage at high temperature and high humidity. Standard test Condition: Temperature: 85°C Relative humidity:85%	limit L: Lower specification limit	n =22 , c=0
Soldering Heat	Time: 1000hrs Evaluates product's ability to withstand soldering heat Standard test conditions Solder temperature: 260±5°C Solder time: 10 seconds		n =22 · c=0



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Supplements

1.Parts

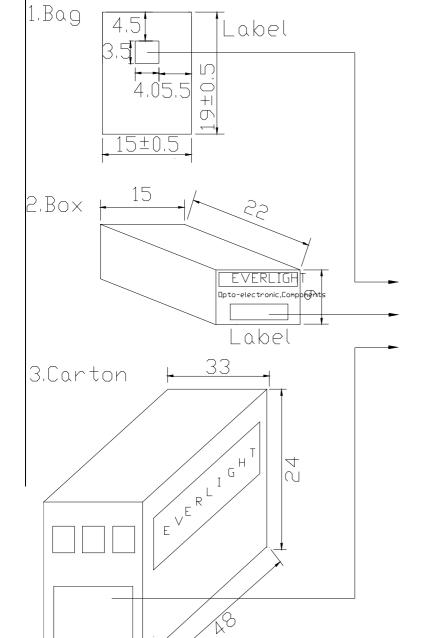
(1) Chip

Type	Material	Peak Wavelength
IR	GaAs or GaAlAs	940 nm
PT	Silicon	860 nm

(2)Material

	Type	Lead frame	Wire	Part Package	Holder
Ī	Material	SPCC	Gold	Epoxy	ABC

Packing Specifications





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CPN : Customer's Product Number

P/N : Product Number

QTY : Packing Quantity

CAT : Ranks

HUE : Peak Wavelength

REF : Reference

LOT NO : Lot Number

MADE IN TAIWAN : Production

place

■Packing Quantity Specification

1.150Pcs/1Bag, 4Bags/1Box

2.10Boxes/1Carton